COMPLIANT

HALOGEN

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### Vishay General Semiconductor

# **Surface Mount Trench MOS Barrier Schottky Rectifier**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	8.0 A			
$V_{RRM}$	50 V			
I <sub>FSM</sub>	120 A			
$V_F$ at $I_F = 8.0$ A $(T_A = 125  ^{\circ}C)$	0.41 V			
T <sub>J</sub> max.	150 °C			
Package	DO-221BC (SMPA)			
Diode variation	Single die			

#### **FEATURES**

- Very low profile typical height of 0.95 mm
- · Ideal for automated placement
- Trench MOS Schottky technology
- Low power losses, high efficiency
- Low forward voltage drop
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

#### **MECHANICAL DATA**

Case: DO-221BC (SMPA)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

M3 suffix meets JESD 201 class 2 whisker test **Polarity:** Color band denotes cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V8PAN50	UNIT	
Device marking code		8N5		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	V	
Maximum DC forward current	I <sub>F</sub> <sup>(1)</sup>	8.0	Α	
	I <sub>F</sub> <sup>(2)</sup>	3.7		
Maximum DC reverse voltage	V <sub>DC</sub>	35	V	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	120	А	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	

#### Notes

- (1) Units mounted on 3 cm x 3 cm Aluminum, 2 oz. PCB
- (2) Free air, mounted on recommended copper pad area



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage	I <sub>F</sub> = 4.0 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.42	-	V
	$I_F = 8.0 \text{ A}$			0.48	0.56	
	I <sub>F</sub> = 4.0 A	T <sub>A</sub> = 125 °C		0.32	-	
	$I_F = 8.0 A$			0.41	0.50	
Reverse current	V <sub>R</sub> = 35 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	25	-	μΑ
	v <sub>R</sub> = 33 v	T <sub>A</sub> = 125 °C		19	-	mA
	V <sub>R</sub> = 50 V	T <sub>A</sub> = 25 °C		-	1500	μΑ
	V <sub>R</sub> = 30 V	T <sub>A</sub> = 125 °C		31	70	mA
Typical junction capacitance	4.0 V, 1 MHz		CJ	1060	-	pF

#### **Notes**

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise specified)			
PARAMETER	SYMBOL V8PAN50		UNIT
Typical thermal resistance	R <sub>0JA</sub> (1)	100	°C/W
Typical trieffial resistance	R <sub>0JM</sub> (2)	5	C/VV

#### Notes

- $^{(1)}$  Free air, mounted on recommended PCB, 2 oz. pad area; thermal resistance  $R_{\theta JA}$  junction to ambient
- Units mounted on 3 cm x 3 cm Aluminum, 2 oz. pad area; thermal resistance  $R_{\theta JM}$  junction to mount

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
V8PAN50-M3/I	0.032	I	14 000	13" diameter plastic tape and reel	

### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise specified)

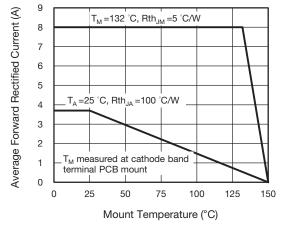


Fig. 1 - Maximum Forward Current Derating Curve

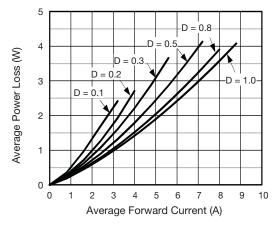


Fig. 2 - Forward Power Loss Characteristics



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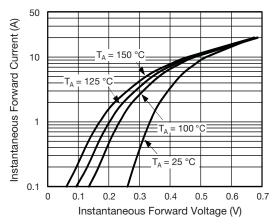


Fig. 3 - Typical Instantaneous Forward Characteristics

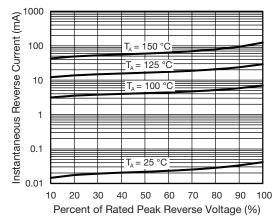


Fig. 4 - Typical Reverse Leakage Characteristics

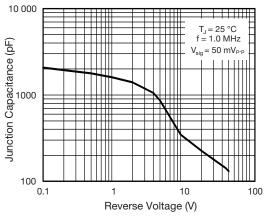


Fig. 5 - Typical Junction Capacitance

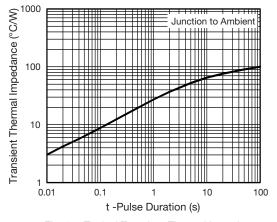


Fig. 6 - Typical Transient Thermal Impedance

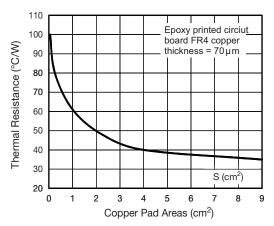


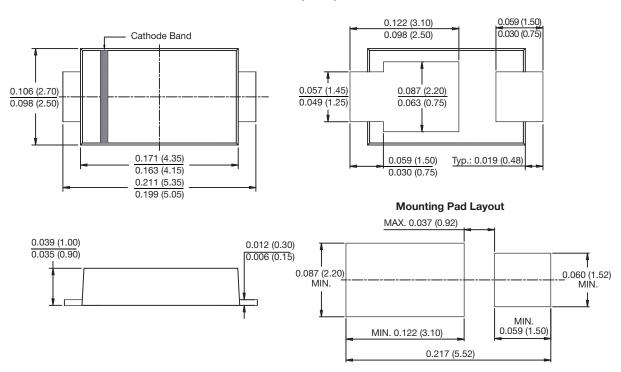
Fig. 7 - Thermal Resistance Junction to Ambient vs. Copper Pad Areas



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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### DO-221BC (SMPA)





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